NSN 5962-01-371-1027

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View Online at https://aerobasegroup.com/nsn/5962-01-371-1027 **Body Length:** 0.540 inches **Body Width:** Between 0.245 inches and 0.300 inches **Body Height:** Between 0.045 inches and 0.100 inches **Maximum Power Dissipation Rating:** 600.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** F-9 mil-m-38510 **Current Rating Per Characteristic:** 105.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** And-or invert gate array **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds delay **Memory Device Type:** Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 flat leads

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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